

**Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units	
Continuous Reverse Voltage	V <sub>R</sub>	40	V	
Continuous Forward Current	I <sub>F</sub>	750	mA	
Forward Voltage @ I <sub>F</sub> = 750mA	V <sub>F</sub>	490	mV	
Average Peak Forward Current; D.C. = 50%	I <sub>FAV</sub>	1500	mA	
Non Repetitive Forward Current	I <sub>FSM</sub>	t ≤ 100μs	12	A
		t ≤ 10ms	5.2	A

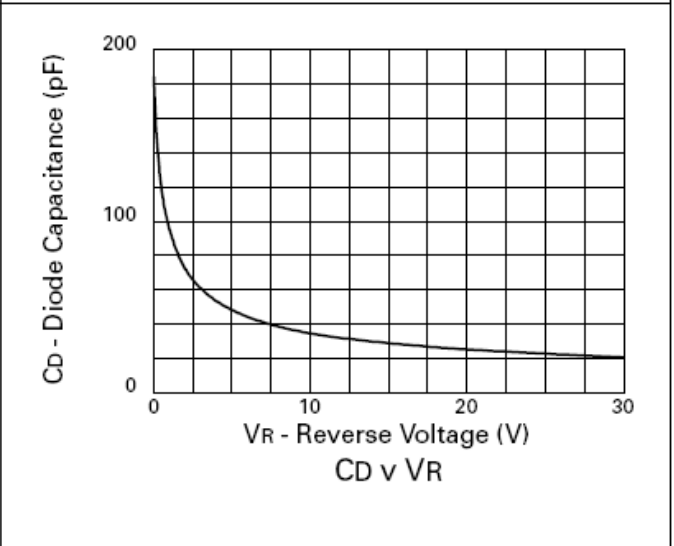
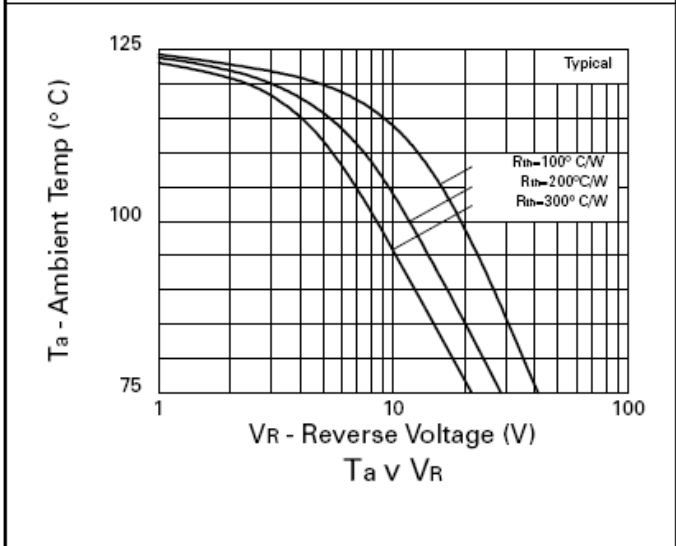
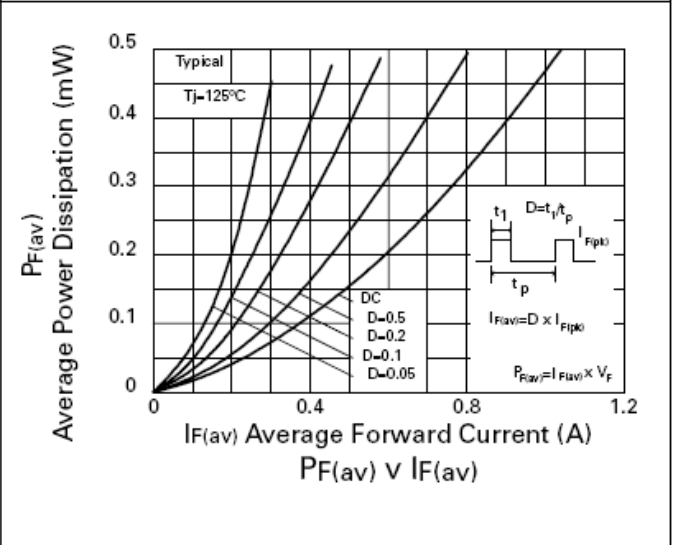
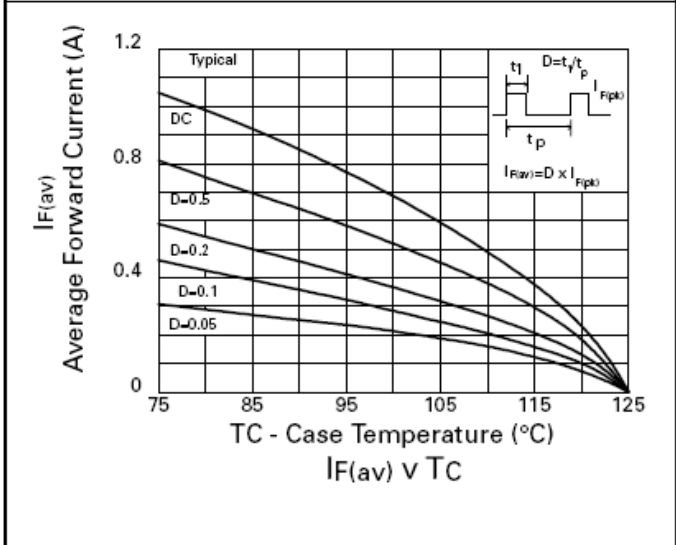
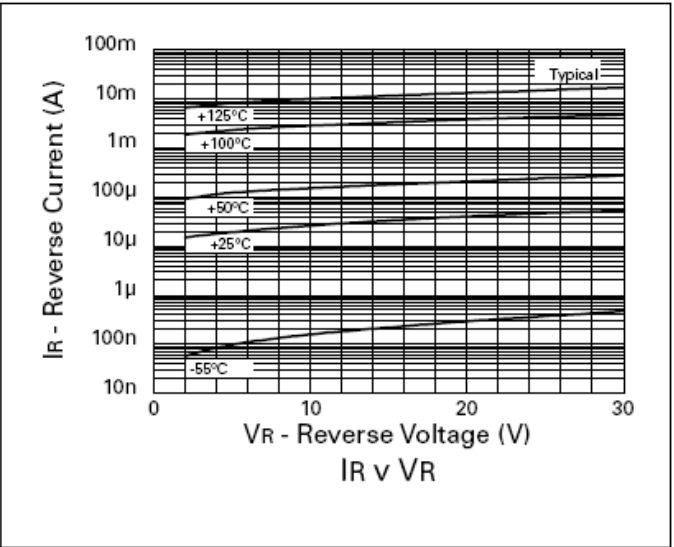
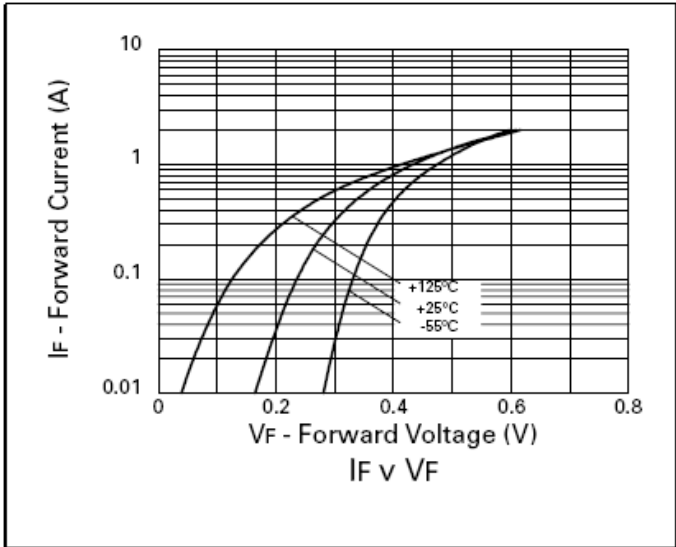
**Thermal Characteristics**

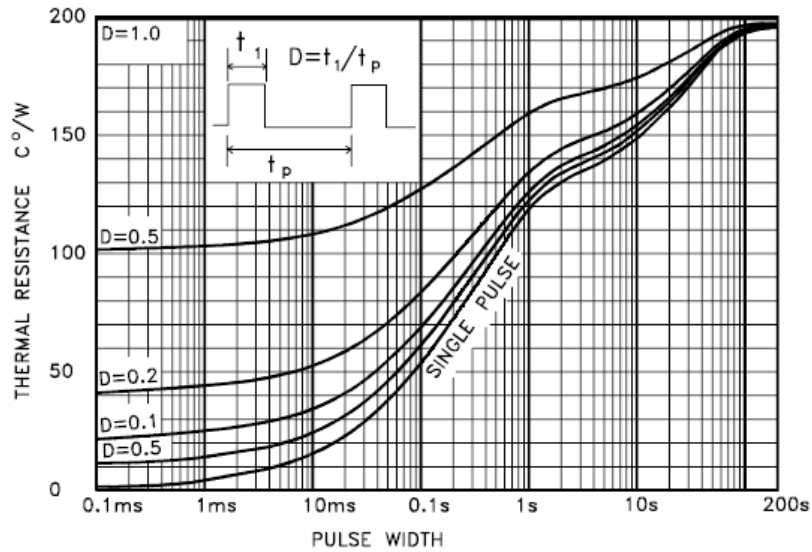
Characteristic	Symbol	Value	Unit
Power Dissipation, T <sub>A</sub> = +25°C	P <sub>D</sub>	500	mW
Junction Temperature	T <sub>J</sub>	125	°C
Storage Temperature Range	T <sub>STG</sub>	-55 to +150	°C

**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Breakdown Voltage	V <sub>(BR)R</sub>	40	60	—	V	I <sub>R</sub> = 300μA
Forward Voltage (Note 5)	V <sub>F</sub>	—	225	280	mV	I <sub>F</sub> = 50mA
		—	235	310		I <sub>F</sub> = 100mA
		—	290	350		I <sub>F</sub> = 250mA
		—	340	420		I <sub>F</sub> = 500mA
		—	390	490		I <sub>F</sub> = 750mA
		—	440	540		I <sub>F</sub> = 1A
		—	530	650		I <sub>F</sub> = 1.5A
Reverse Current (Note 6)	I <sub>R</sub>	—	50	100	μA	V <sub>R</sub> = 30V
Diode Capacitance	C <sub>D</sub>	—	25	—	pF	f = 1MHz, V <sub>R</sub> = 25V
Reverse Recovery Time	T <sub>rr</sub>	—	12	—	ns	Switched from I <sub>F</sub> = 500mA to I <sub>R</sub> = 500mA Measured @ I <sub>R</sub> = 50mA

Notes: 5. Measured under pulsed conditions. Pulse width = 300μs. Duty cycle ≤ 2%.  
6. Short duration pulse test used to minimize self-heating effect.



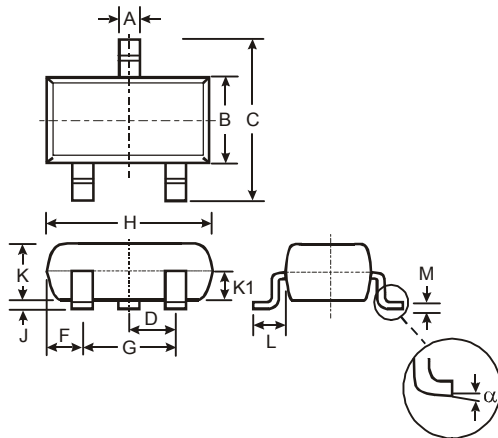


MAXIMUM TRANSIENT THERMAL RESISTANCE\*

\* Reference above figure, devices were mounted on a 15mmx15mm ceramic substrate.

### Package Outline Dimensions

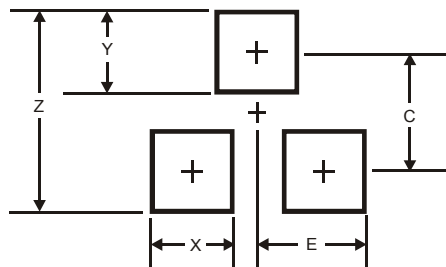
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



SOT23			
Dim	Min	Max	Typ
A	0.37	0.51	0.40
B	1.20	1.40	1.30
C	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
H	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.903	1.10	1.00
K1	-	-	0.400
L	0.45	0.61	0.55
M	0.085	0.18	0.11
alpha	0°	8°	-
All Dimensions in mm			

### Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for latest version.



Dimensions	Value (in mm)
Z	2.9
X	0.8
Y	0.9
C	2.0
E	1.35

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